

SEMICONDUCTOR

P1086

P-Channel Switch

- This device is designed for low level analog switching sample and hold circuits and chopper stabilized amplifiers.
- Sourced from process 88.



Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{DG}	Drain-Gate Voltage	- 30	V
V _{GS}	Gate-Source Voltage	30	V
I _{GF}	Forward Gate Current	50	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

NOTES:

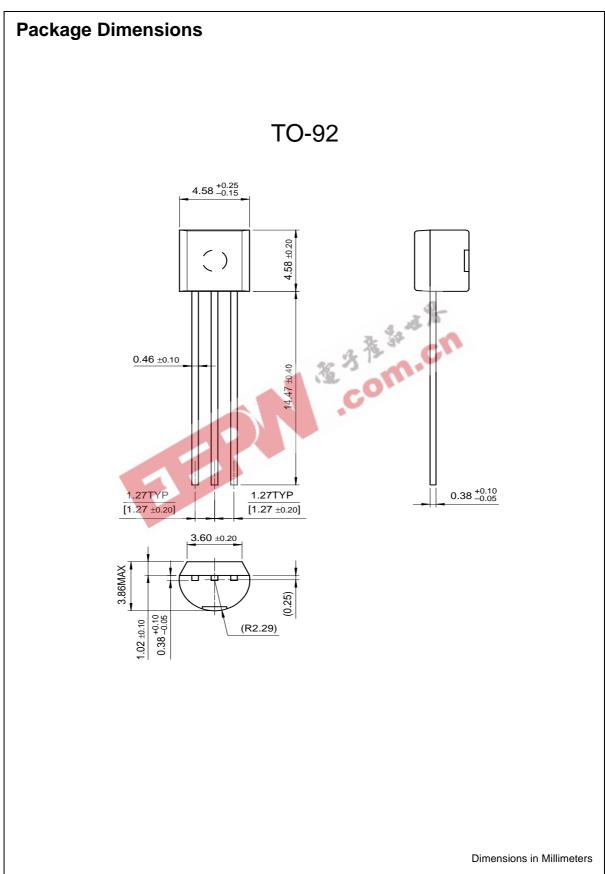
These ratings are based on a maximum junction temperature of 150 degrees C.
 These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition		Min.	Тур.	Max.	Units
BV _{GSS}	Gate-Source Breakdown Voltage	$V_{DS} = 0V, IG = 1\mu A$		30			V
I _{GSS}	Gate Reverse Current	V _{GS} = 15V				2	nA
I _D (off)	Drain Cutoff Leakage Current	V _{DS} = 15V				10	nA
		$V_{GS} = 12V$	T = +85°C			0.5	μΑ
I _{DGO}	Drain-Gate Leakage Current	V _{DG} = 15V				2	NА
		I _S = 0	T = +85°C			0.1	μΑ
I _{DSS}	Zero-Gate Voltage Drain Current	$V_{DS} = 20V, V_{GS} = 0V$		10			mA
V _{GS} (off)	Gate-Source Cutoff Voltage	$V_{DS} = 15V, I_{D} = 1\mu A$				10	V
V _{DS} (on)	Drain-Source On Voltage	$V_{GS} = 0V, I_D = 6mA$				0.5	V
r _{DS} (on)	Drain-Source On Resistance	$V_{GS} = 0V, I_D = 1mA$				75	Ω
r _{ds} (on)	Drain-Source On Resistance	$V_{GS} = 0V, I_D = 0, f = 1kHz$				75	Ω
C _{iss}	Input Capacitance	V _{DS} = 15V, V _{GS} = 0V, f = 1MHz				45	pF
C _{rss}	Reverse Transfer Capacitance	$V_{DS} = 0V, V_{GS} = 12V, f = 1MHz$				10	pF
t _d (on)	Trun On Time	$V_{DD} = -6V$ $V_{GS}(off) = +12V$ $R_{L} = 910\Omega$ $I_{D}(on) = 6mA$				15	ns
t _r	Rise Time					20	ns
t _d (off)	Trun Off Time					15	ns
t _f	Fall Time					50	ns

Thermal Characteristics $T_{A}\text{=}25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Max.	Units
PD	Total Device Dissipation		mW
	Derate above 25°C	2.8	mW/°C
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case	125	°C/W
R _{0JA}	Thermal Resistance, Junction to Ambient	357	°C/W



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Across the board	Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
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Programmable A	ctive Droop™	OPTOPLANAR™	SMART START™	

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